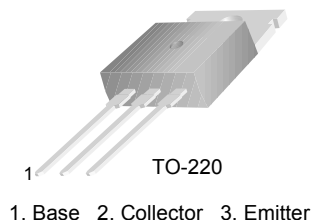


D45C8

PNP Power Amplifier

- Sourced from process 5P.



Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	-60	V
I_C	Collector Current - Continuous	-4.0	A
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

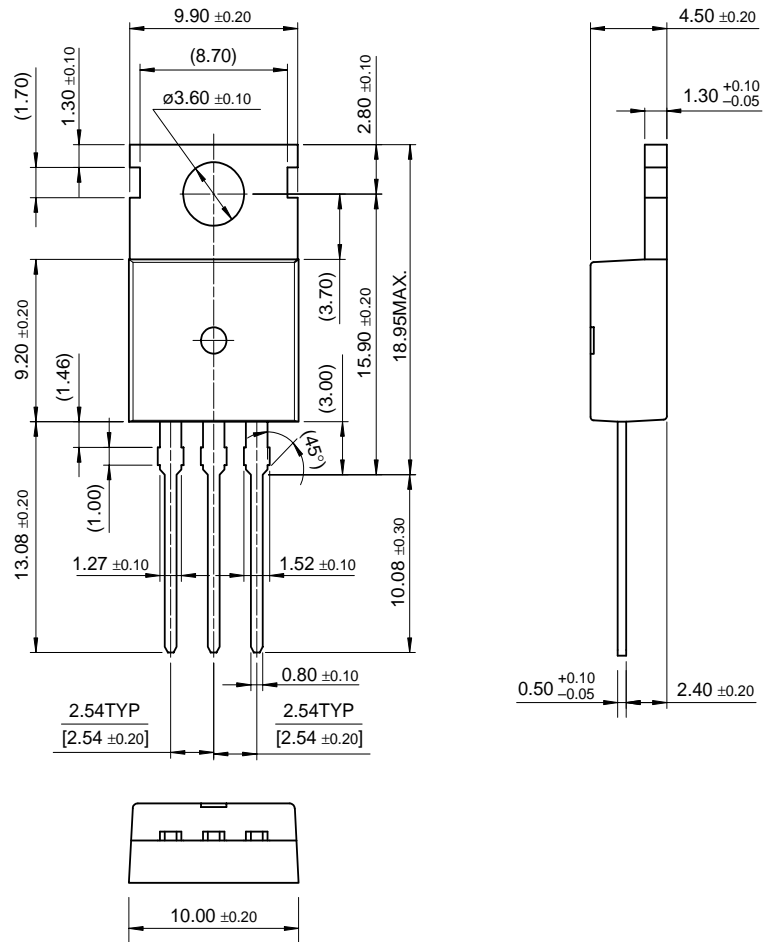
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -100\text{mA}, I_B = 0$	-60		V
I_{CES}	Collector-Cutoff Current	$V_{CB} = -70\text{V}, I_E = 0$		-10	μA
I_{EBO}	Emitter-Cutoff Current	$V_{EB} = -5.0\text{V}, I_B = 0$		-100	μA
On Characteristics *					
h_{FE}	DC Current Gain	$V_{CE} = -1\text{V}, I_C = -0.2\text{A}$ $V_{CE} = -1\text{V}, I_C = -2.0\text{A}$	40 20	120	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -1.0\text{A}, I_B = -50\text{mA}$		-0.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -1.0\text{A}, I_B = -100\text{mA}$		-1.3	V
Small Signal Characteristics					
f_T	Current Gain Bandwidth Product	$I_C = -20\text{mA}, V_{CE} = -4.0\text{V}$	32		pF

Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	60 480	W $\text{mW}/^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	2.1	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	$^\circ\text{C}/\text{W}$

Mechanical Dimensions

TO-220



Dimensions in Millimeters

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